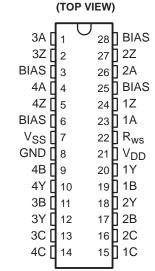
**DW PACKAGE** 

- Four Independent Drivers and Receivers
- Driver Slew Rate Controlled by a Single Resistor
- Fast Driver Transition Times Down to 1.5 μs and Receiver Transition Times of 20 ns Typ
- Internal Thermal-Overload Protection
- RS-423-B Inputs and Outputs Designed to Withstand ±25 V
- ESD Protection Exceeds 2000 V Per MIL-STD-833C Method 3015
- LinBICMOS™ Process Technology

## description

The SN75LBC784 performs as four independent RS-423-B driver/receiver pairs designed to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE) at rates up to 120 kbps and distances to 1.2 km. The SN75LBC784 provides an upgrade to the RS-232 serial interface and can be backward compatible with existing serial ports while offering the higher performance required by new faster peripherals, such as v.34 (v.fast) modems. The RS-232 standard, and subsequent revisions, only support data rates up to 20 kbps over about 15 meters of cable. For RS-423-B the data rate is increased to 120 kbps and transmission distance to 1.2 km by reducing the maximum output signal swing, increasing the driver output current, and reducing the receiver input voltage thresholds.



#### **FUNCTION TABLE**

INPUTS			OUT	PUTS
Α	В	С	Z	Υ
L	L	Н	Н	Н
Н	L	Н	Н	L
L	Н	L	L	Н
Н	Н	L	L	L
L	L	L	?	Н
Н	L	L	?	L
L	Н	Н	?	Н
Н	Н	Н	?	L

H = high level, L = low level,

X = irrelevant, Z = high impedance (off)

? = indeterminate

The receivers consist of differential comparators with hysteresis and resistive attenuation on the inputs. The resistive attenuation improves the input common mode range and also provides additional protection from ESD and over-voltage stress. The differential and common mode input impedances are sufficiently high to meet RS-423-B. When a differential voltage input of 500 mV is applied across the entire common mode range ( see Figure 5), the receiver characteristics and bias voltage allow the receiver to remain in its intended binary state.

The drivers meet all RS-423-B specifications with built-in current limits and thermal-overload protection. Slew-rate controlling circuitry is included in the design, which is adjusted to suit the application by means of an external resistor ( $R_{WS}$ ). The slew rate controlling circuitry also has a default mode – if the  $R_{WS}$  pin is shorted to 5 V externally, the transistion time defaults to approximately 1.5 ms. The BIAS input, when shorted to 5 V externally, provides the internal node voltages. The receiver is compatible to RS-232 with the use of external input resistors to meet the RS-232 input resistance specification of 3 k $\Omega$  to 7 k $\Omega$ .

The SN75LBC784 is characterized for operation over the temperature range of 0°C to 70°C.



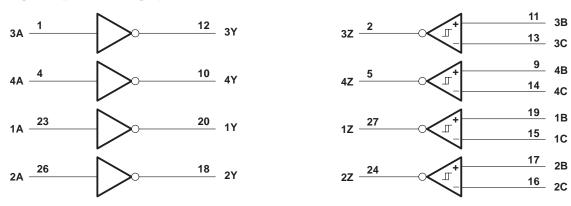
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SLLS187A - NOVEMBER 1994 - REVISED AUGUST 1995

# logic diagram (positive logic)



# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Positive supply voltage, V <sub>DD</sub> (see Note 1)	
Negative supply voltage, V <sub>SS</sub>	14 V
Bias voltage, V <sub>bias</sub>	5.75 V
Receiver input voltage range	
Driver input voltage range	0.5 V to 5.75 V
Driver output voltage range (supplies at 0 V)	
Driver output voltage range (supplies at ±12 V)	25 V to 25 V
Continuous power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	0°C to 70°C
Storage temperature range	
Case temperature for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to network ground terminal.

### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR <sup>†</sup> ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING
DW	1348 mW	10.8 mW/°C	862 mW

<sup>†</sup>Derating factors are the inverse of the junction-to-ambient thermal resistance when board-mounted with no air flow.

## recommended operating conditions

					MIN	NOM	MAX	UNIT
Supply voltage, V <sub>DD</sub>					10.8	12	13.2	V
Supply voltage, VSS					-10.8	-12	-13.2	V
Bias voltage, V <sub>bias</sub>					2	5	5.5	V
High-level input voltage, VIH	Driver				2			V
Low-level input voltage, V <sub>IL</sub>	Driver						0.8	V
High-level output current, IOH	Receive	r					-4	mA
Low-level output current, IOL	Receive	r					4	mA
Rws slew rate control resistor					20	82	820	kΩ
Operating free-air temperature, TA					0		70	°C



### **DRIVER SECTION**

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature,  $V_{DD}$  = 10.8 V to 13.2 V,  $V_{SS}$  = -10.8 V to -13.2 V,  $T_A$  = 0°C to 70°C (unless otherwise noted)

PARAMETER		TEST CO	TEST CONDITIONS		TYP	MAX	UNIT
Vон	High-level output voltage	Open circuit or R <sub>L</sub> = 4	<b>1</b> 50 Ω	4	5.5	6	V
VOL	Low-level output voltage	Open circuit or R <sub>L</sub> = 4	<b>1</b> 50 Ω	-6	-5.5	-4	V
lіН	High-level input current	$V_{ } = 2.4 \text{ V to } 5.5 \text{ V}$				100	μΑ
I <sub>IL</sub>	Low-level input current	V <sub>I</sub> = 0 V to 0.8 V		-100			μΑ
IO	Output leakage current	$V_{DD} = V_{SS} = 0$ ,	V <sub>O</sub> = ±6 V	-100		100	μΑ
IOS(H)	High-level short circuit output current	V <sub>I</sub> = 5 V,	V <sub>O</sub> = 0	15		45	mA
IOS(L)	Low-level short circuit output current	V <sub>I</sub> = 0,	V <sub>O</sub> = 0	-45		-15	mA
la-a	Cumply ourrant	No load			10	12	mA
IDD	Supply current	$R_L = 450 \Omega$			60	70	IIIA
laa	Cumply ourrant	No load			-10	-12	mA
Iss	Supply current	$R_L = 450 \Omega$	•		-60	-70	IIIA
I <sub>bias</sub>	Bias current					400	μΑ

switching characteristics over recommended ranges of supply voltage and operating free-air temperature,  $V_{DD}$  = 10.8 V to 13.2 V,  $V_{SS}$  = -10.8 V to -13.2 V,  $T_A$  = 0°C to 70°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
			$R_{WS} = 0 k\Omega$		1.5		
			$R_{WS} = 20 \text{ k}\Omega$	1.5	2.1	2.7	
tTLH	Transition time, low-to-high level (see Figure 1)		$R_{WS} = 82 \text{ k}\Omega$	5	8	11	μs
			$R_{WS} = 820 \text{ k}\Omega$		80		
		$R_L = 450 \Omega$ , $C_L = 50 pF$ ,	$R_{WS} = 0 k\Omega$		1.5		
		$V_{WS} = 5 V$	$R_{WS} = 20 \text{ k}\Omega$	1.5	2.1	2.7	
tTHL	Transition time, high-to-low level (see Figure 1)		$R_{WS} = 82 \text{ k}\Omega$	5	8	11	μs
			$R_{WS} = 820 \text{ k}\Omega$		80		
SR	Output slew rate		Rws = $20 \text{ k}\Omega$			15	V/μs
t <sub>sk</sub>	Output skew (see Figure 4)  tpHL - tpLH		$R_{WS} = 82 \text{ k}\Omega$			1	μs

### RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature,  $V_{DD}$  = 10.8 V to 13.2 V,  $V_{SS}$  = -10.8 V to -13.2 V,  $T_A$  = 0°C to 70°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
\/	Desitive input threshold voltage					200	mV
V <sub>IT+</sub> Positive input threshold voltage		With 500 $\Omega$ series resist	tor			400	mv
Manager Sanad through ald a alterna						-200	mV
VIT-	Negative input threshold voltage	With 500 $\Omega$ series resist	tor			-400	mv
l. Innut current	Input ourrent	V <sub>I</sub> = 10 V	Other input to CND		1.3	3.25	mA
l''	Input current $V_{I} = -10 \text{ V}$ Other input to GND	-3.25	-1.3		IIIA		
V <sub>hys</sub>	Hysteresis (V <sub>IT+</sub> – V <sub>IT</sub> _)		-	20	40	150	mV
V	High level output voltage (e.g. Note 2)	$I_{O} = -20 \mu\text{A}$	$I_{O} = -20 \mu\text{A}$			5	V
VOH	High-level output voltage (see Note 2)	$I_O = -4 \text{ mA}$		2.4		5	V
VOL	Low-level output voltage	I <sub>O</sub> = 20 μA to 4 mA				0.4	V
I <sub>RX</sub>	RX short circuit current					50	mA
$V_{\text{ID}}$	Differential input voltage	Receiver inputs open circuit		1.6	2.1	2.6	V
Vofs	Fail safe output voltage	See Note 3	-	3.5			V

NOTES: 2. Device has an internal RX supply regulator. Maximum RX logic output voltage under no load is thus defined by an internal voltage value. This is nominally set to 4.5 V with a tolerance of ±5%.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

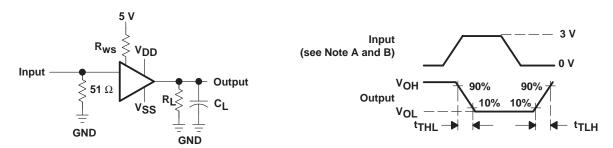
test conditions:  $V_{DD}$  = 10.8 V to 13.2 V,  $V_{SS}$  = -10.8 V to -13.2 V,  $T_A$  = 0°C to 70°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT
<sup>t</sup> PLH	Propagation Delay time low-to-high (see Figure 2)			0.15	1	
tPHL	Propagation delay time high-to-low (see Figure 2)	C 50 pF	0.15	0.15	'	μs
tTHL	Transition time high-to-low (see Figure 3)	$C_L = 50 \text{ pF}$		20	200	
tTLH	Transition time low-to-high (see Figure 3)		20		200	ns



<sup>3.</sup> One input at ground, other input open circuit,  $I_{O} = -20 \,\mu\text{A}$ , or both open circuit.

## PARAMETER MEASUREMENT INFORMATION



**Figure 1. Driver Transition Times** 

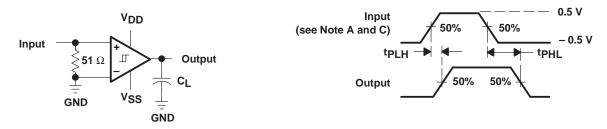


Figure 2. Receiver Propagation Delay Times

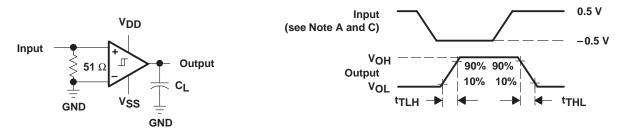
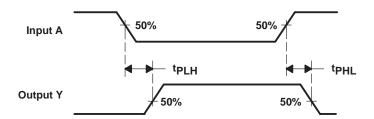


Figure 3. Receiver Transition Times

NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. The input pulse is supplied by a generator having the following characteristics:  $t_{\Gamma} \le 10$  nS,  $t_{f} < 10$  nS,  $t_{Q} = 50$   $\Omega$ , PRR  $\ge 5$  kHz, duty cycle 50%,  $V_{max} = 3$  V,  $V_{min} = 0$  V.
- C. The input pulse is supplied by a generator having the following characteristics:  $t_f \le 10$  nS,  $t_f < 10$

# PARAMETER MEASUREMENT INFORMATION



**Figure 4. Skew Definition Times** 

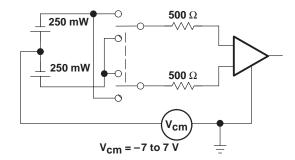


Figure 5. Receiver Input Balance Test

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